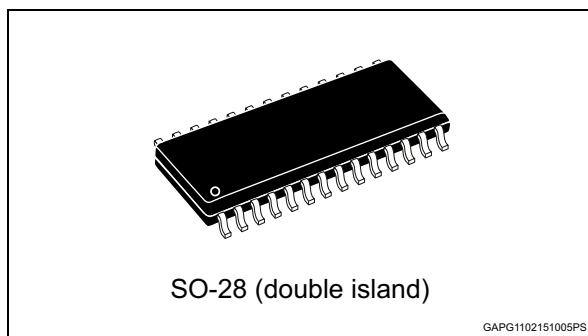


## Quad smart power solid state relay for complete H-bridge configurations

Datasheet - production data



- Thermal shutdown indication on both the high and low-side switches

### Applications

- DC motor driving in full or half bridge configuration
- All types of resistive, inductive and capacitive loads

### Description

The VN5770AKP-E is a device formed by three monolithic chips housed in a standard SO-28 package: a double high-side and two low-side switches. The double high-side is made using STMicroelectronics® VIPower® M0-5 technology, while the low-side switches are fully protected VIPower M0-3 OMNIFET II. This device is suitable to drive a DC motor in a bridge configuration as well as to be used as a quad switch for any low voltage application.

The dual high-side switches integrate built in non latching thermal shutdown with thermal hysteresis. An output current limiter protects the device in overload condition. In case of long overload duration, the device limits the dissipated power to a safe level up to thermal shutdown intervention. An analog current sense pin delivers a current proportional to the load current (according to a known ratio) and indicates overtemperature shutdown of the relevant high-side switch through a voltage flag.

The low-side switches have built in non latching thermal shutdown with thermal hysteresis, linear current limitation and overvoltage clamping.

Fault feedback for overtemperature shutdown of the low-side switch is indicated by the relevant input pin current consumption going up to the fault sink current flag.

### Features

| Type        | $R_{DS(on)}$          | $I_{OUT} (typ)$ | $V_{CC}$ |
|-------------|-----------------------|-----------------|----------|
| VN5770AKP-E | 280 mΩ <sup>(1)</sup> | 8.5 A           | 36 V     |

1. Total resistance of one side in bridge configuration

- ECOPACK®: lead free and RoHS compliant
- Automotive Grade: compliance with AEC guidelines
- General features
  - Inrush current management by active power limitation on the high-side switches
  - Very low standby current
  - Very low electromagnetic susceptibility
  - Compliance with European directive 2002/95/EC
- Protection
  - High-side drivers undervoltage shutdown
  - Overvoltage clamp
  - Output current limitation
  - High and low-side overtemperature shutdown
  - Short circuit protection
  - ESD protection
- Diagnostic functions
  - Proportional load current sense

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# 1 Block diagram and pin descriptions

Figure 1. Block diagram

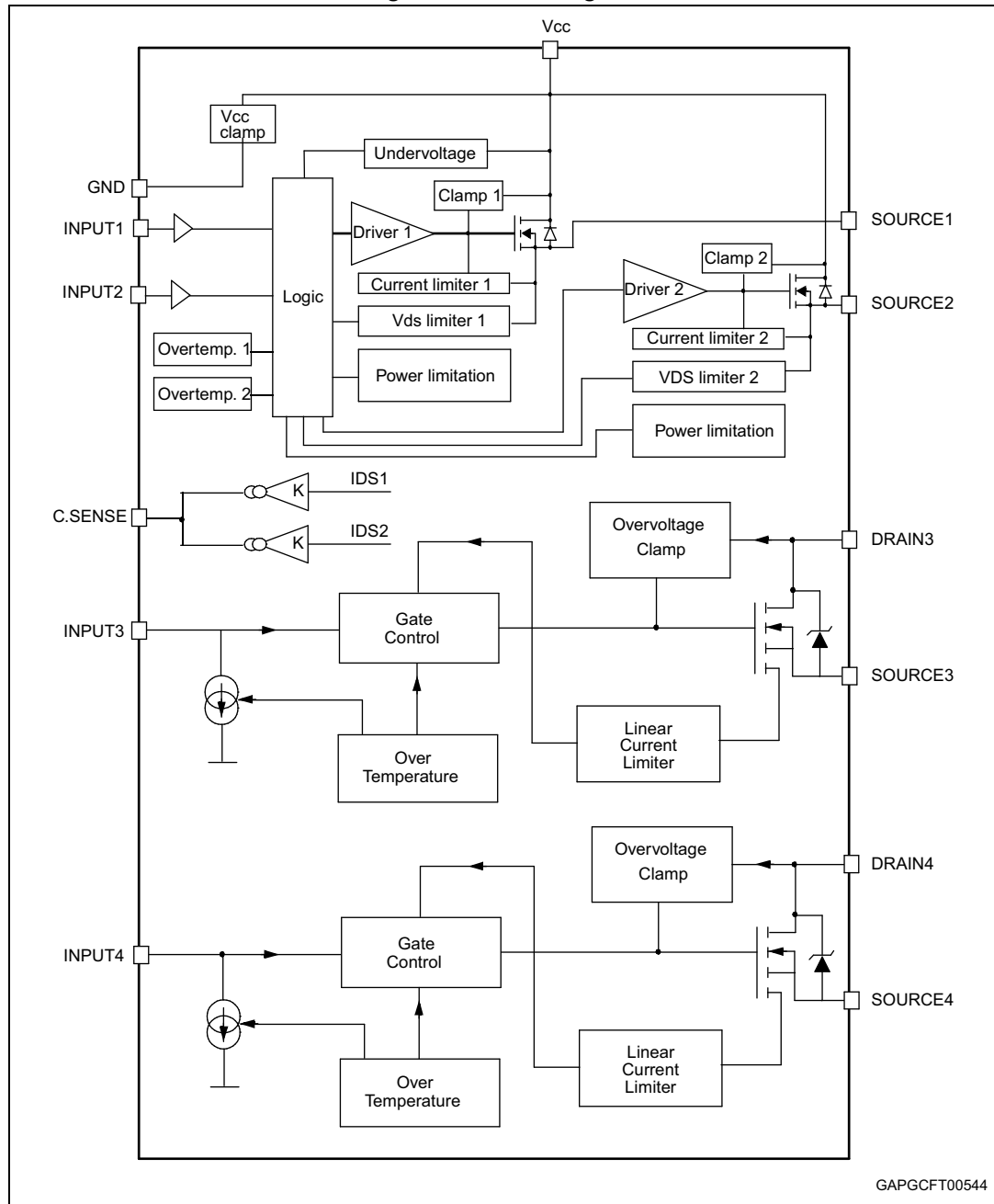


Table 1. Pin descriptions

| No             | Name            | Function                                                                         |
|----------------|-----------------|----------------------------------------------------------------------------------|
| 1, 3, 25, 28   | DRAIN 3         | Drain of switch 3 (low-side switch)                                              |
| 2              | INPUT 3         | Input of switch 3 (low-side switch)                                              |
| 4, 11          | N.C.            | Not connected                                                                    |
| 5, 10, 19, 24  | V <sub>CC</sub> | Drain of switches 1 and 2 (high-side switches) and power supply voltage          |
| 6              | GND             | Ground of switches 1 and 2 (high-side switches)                                  |
| 7              | INPUT 1         | Input of switch 1 (high-side switches)                                           |
| 8              | INPUT 2         | Input of switch 2 (high-side switch)                                             |
| 9              | CURRENT SENSE   | Analog current sense pin, it delivers a current proportional to the load current |
| 12, 14, 15, 18 | DRAIN 4         | Drain of switch 4 (low-side switch)                                              |
| 13             | INPUT 4         | Input of switch 4 (low-side switch)                                              |
| 16, 17         | SOURCE 4        | Source of switch 4 (low-side switch)                                             |
| 20, 21         | SOURCE 2        | Source of switch 2 (high-side switch)                                            |
| 22, 23         | SOURCE 1        | Source of switch 1 (high-side switch)                                            |
| 26, 27         | SOURCE 3        | Source of switch 3 (low-side switch)                                             |

Figure 2. Configuration diagram (top view)

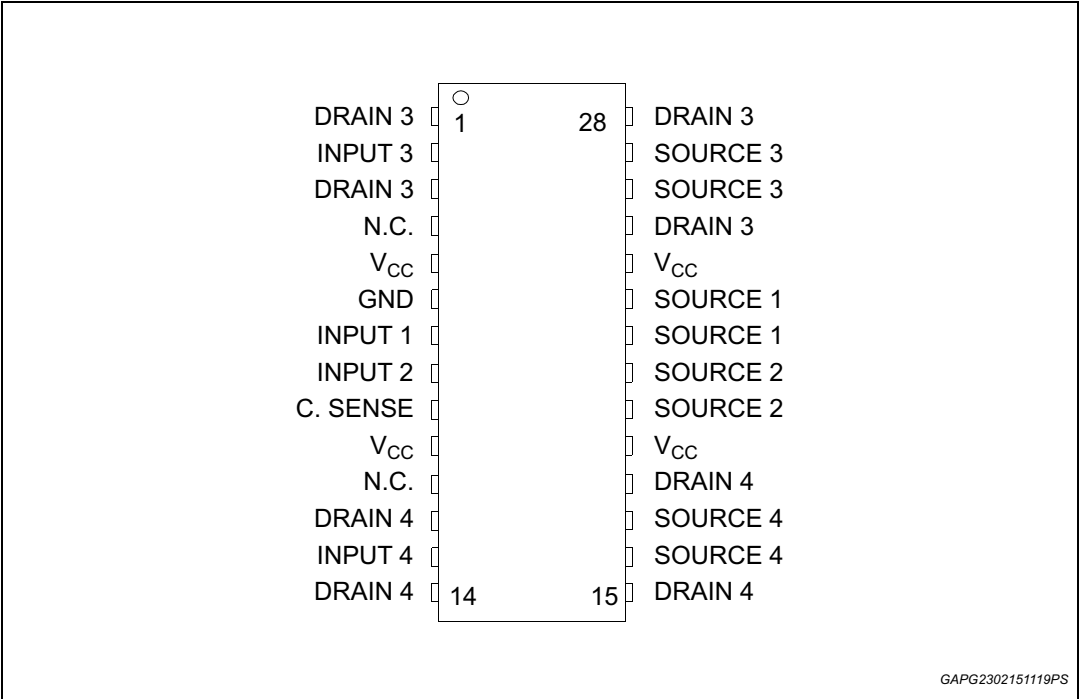


Table 2. Thermal data

| Symbol         | Parameter                                           | Max value                     | Unit |
|----------------|-----------------------------------------------------|-------------------------------|------|
| $R_{thj-case}$ | Thermal resistance junction-lead (high-side switch) | 10                            | °C/W |
| $R_{thj-case}$ | Thermal resistance junction-lead (low-side switch)  | 7                             | °C/W |
| $R_{thj-amb}$  | Thermal resistance junction-ambient                 | See <a href="#">Figure 39</a> | °C/W |

## 2 Absolute maximum ratings

Stressing the device above the rating listed in [Table 3](#) and [Table 4](#) may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is not implied. Exposure to the conditions in [Section 2.1: Absolute maximum ratings](#) for extended periods may affect device reliability.

### 2.1 Absolute maximum ratings

Table 3. Dual high-side switch

| Symbol       | Parameter                                                                                                                                                  | Value                        | Unit             |
|--------------|------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------|------------------|
| $V_{CC}$     | DC supply voltage                                                                                                                                          | 41                           | V                |
| $-V_{CC}$    | Reverse DC supply voltage                                                                                                                                  | 0.3                          | V                |
| $-I_{GND}$   | DC reverse ground pin current                                                                                                                              | 200                          | mA               |
| $I_{OUT}$    | DC output current                                                                                                                                          | Internally limited           | A                |
| $-I_{OUT}$   | Reverse DC output current                                                                                                                                  | -12                          | A                |
| $I_{IN}$     | DC input current                                                                                                                                           | -1 to 10                     | mA               |
| $I_{CSD}$    | DC current sense disable input current                                                                                                                     | -1 to 10                     | mA               |
| $V_{CSENSE}$ | Current sense maximum voltage                                                                                                                              | $V_{CC}-41$<br>$+V_{CC}$     | V<br>V           |
| $E_{MAX}$    | Maximum switching energy (single pulse)<br>( $L = 3.7$ mH; $R_L = 0$ $\Omega$ ; $V_{bat} = 13.5$ V; $T_{jstart} = 150$ °C;<br>$I_{OUT} = I_{limL}(Typ.)$ ) | 32                           | mJ               |
| $V_{ESD}$    | Electrostatic discharge (Human Body Model: $R = 1.5$ K $\Omega$ ;<br>$C = 100$ pF)<br>– INPUT<br>– CURRENT SENSE<br>– OUTPUT<br>– $V_{CC}$                 | 4000<br>2000<br>5000<br>5000 | V<br>V<br>V<br>V |
| $V_{ESD}$    | Charge device model (CDM-AEC-Q100-011)                                                                                                                     | 750                          | V                |
| $T_j$        | Junction operating temperature                                                                                                                             | -40 to 150                   | °C               |
| $T_{stg}$    | Storage temperature                                                                                                                                        | -55 to 150                   | °C               |



Table 4. Low-side switch

| Symbol         | Parameter                                                                            | Value              | Unit       |
|----------------|--------------------------------------------------------------------------------------|--------------------|------------|
| $V_{DSn}$      | Drain-source voltage ( $V_{INn} = 0$ V)                                              | Internally clamped | V          |
| $V_{INn}$      | Input voltage                                                                        | Internally clamped | V          |
| $I_{INn}$      | Input current                                                                        | +/-20              | mA         |
| $R_{IN\ MINn}$ | Minimum input series impedance                                                       | 220                | $\Omega$   |
| $I_{Dn}$       | Drain current                                                                        | Internally limited | A          |
| $I_{Rn}$       | Reverse DC output current                                                            | -12                | A          |
| $V_{ESD1}$     | Electrostatic discharge ( $R = 1.5\ K\Omega$ , $C = 100\ pF$ )                       | 4000               | V          |
| $V_{ESD2}$     | Electrostatic discharge on output pins only<br>( $R = 330\ \Omega$ , $C = 150\ pF$ ) | 16500              | V          |
| $P_{tot}$      | Total dissipation at $T_c = 25\ ^\circ C$                                            | 4                  | W          |
| $T_j$          | Operating junction temperature                                                       | Internally limited | $^\circ C$ |
| $T_c$          | Case operating temperature                                                           | Internally limited | $^\circ C$ |
| $T_{stg}$      | Storage temperature                                                                  | -55 to 150         | $^\circ C$ |

### 3 Electrical characteristics

#### 3.1 Electrical characteristics for dual high-side switch

Values specified in this section are for  $8\text{ V} < V_{CC} < 36\text{ V}$ ;  $-40\text{ }^{\circ}\text{C} < T_j < 150\text{ }^{\circ}\text{C}$ , unless otherwise specified (for each channel).

**Table 5. Power section**

| Symbol        | Parameter                                      | Test conditions                                                                                                         | Min. | Typ.             | Max.             | Unit          |
|---------------|------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------|------|------------------|------------------|---------------|
| $V_{CC}$      | Operating supply voltage                       |                                                                                                                         | 4.5  | 13               | 36               | V             |
| $V_{USD}$     | Undervoltage shutdown                          |                                                                                                                         |      | 3.5              | 4.5              | V             |
| $V_{USDhyst}$ | Undervoltage shutdown hysteresis               |                                                                                                                         |      | 0.5              |                  | V             |
| $R_{ON}$      | On-state resistance                            | $I_{OUT} = 3\text{ A}$ ; $T_j = 25\text{ }^{\circ}\text{C}$                                                             |      | 160              |                  | m $\Omega$    |
|               |                                                | $I_{OUT} = 3\text{ A}$ ; $T_j = 150\text{ }^{\circ}\text{C}$                                                            |      |                  | 320              | m $\Omega$    |
|               |                                                | $I_{OUT} = 3\text{ A}$ ; $V_{CC} = 5\text{ V}$ ; $T_j = 25\text{ }^{\circ}\text{C}$                                     |      |                  | 210              | m $\Omega$    |
| $V_{clamp}$   | Clamp Voltage                                  | $I_S = 20\text{ mA}$                                                                                                    | 41   | 46               | 52               | V             |
| $I_S$         | Supply current                                 | Off-state; $V_{CC} = 13\text{ V}$ ; $T_j = 25\text{ }^{\circ}\text{C}$ ;<br>$V_{IN} = V_{OUT} = V_{SENSE} = 0\text{ V}$ |      | 2 <sup>(1)</sup> | 5 <sup>(1)</sup> | $\mu\text{A}$ |
|               |                                                | On-state; $V_{CC} = 13\text{ V}$ ; $V_{IN} = 5\text{ V}$ ;<br>$I_{OUT} = 0\text{ A}$                                    |      | 3                | 6                | mA            |
| $I_{L(off)}$  | Off-state output current <sup>(2)</sup>        | $V_{IN} = V_{OUT} = 0\text{ V}$ ; $V_{CC} = 13\text{ V}$ ;<br>$T_j = 25\text{ }^{\circ}\text{C}$                        | 0    |                  | 3                | $\mu\text{A}$ |
|               |                                                | $V_{IN} = V_{OUT} = 0\text{ V}$ ; $V_{CC} = 13\text{ V}$ ;<br>$T_j = 125\text{ }^{\circ}\text{C}$                       | 0    |                  | 5                | $\mu\text{A}$ |
| $V_F$         | Output - $V_{CC}$ diode voltage <sup>(2)</sup> | $-I_{OUT} = 3\text{ A}$ ; $T_j = 150\text{ }^{\circ}\text{C}$                                                           |      |                  | 0.7              | V             |

1. PowerMOS leakage included

2. For each channel

**Table 6. Switching ( $V_{CC} = 13\text{ V}$ )**

| Symbol                | Parameter                                 | Test conditions                                           | Min. | Typ.                          | Max. | Unit             |
|-----------------------|-------------------------------------------|-----------------------------------------------------------|------|-------------------------------|------|------------------|
| $t_{d(on)}$           | Turn-on delay time                        | $R_L = 4.3\text{ }\Omega$ (see <a href="#">Figure 3</a> ) | —    | 15                            | —    | $\mu\text{s}$    |
| $t_{d(off)}$          | Turn-off delay time                       | $R_L = 4.3\text{ }\Omega$ (see <a href="#">Figure 3</a> ) | —    | 10                            | —    | $\mu\text{s}$    |
| $(dV_{OUT}/dt)_{on}$  | Turn-on voltage slope                     | $R_L = 4.3\text{ }\Omega$                                 | —    | See <a href="#">Figure 15</a> | —    | V/ $\mu\text{s}$ |
| $(dV_{OUT}/dt)_{off}$ | Turn-off voltage slope                    | $R_L = 4.3\text{ }\Omega$                                 | —    | See <a href="#">Figure 17</a> | —    | V/ $\mu\text{s}$ |
| $W_{ON}$              | Switching energy losses during $t_{won}$  | $R_L = 4.3\text{ }\Omega$ (see <a href="#">Figure 3</a> ) | —    | 0.16                          | —    | mJ               |
| $W_{OFF}$             | Switching energy losses during $t_{woff}$ | $R_L = 4.3\text{ }\Omega$ (see <a href="#">Figure 3</a> ) | —    | 0.08                          | —    | mJ               |

Table 7. Logic input

| Symbol        | Parameter                | Test conditions         | Min. | Typ. | Max. | Unit          |
|---------------|--------------------------|-------------------------|------|------|------|---------------|
| $V_{IL}$      | Input low level voltage  |                         |      |      | 0.9  | V             |
| $I_{IL}$      | Low level input current  | $V_{IN} = 0.9\text{ V}$ | 1    |      |      | $\mu\text{A}$ |
| $V_{IH}$      | Input high level voltage |                         | 2.1  |      |      | V             |
| $I_{IH}$      | High level input current | $V_{IN} = 2.1\text{ V}$ |      |      | 10   | $\mu\text{A}$ |
| $V_{I(hyst)}$ | Input hysteresis voltage |                         | 0.25 |      |      | V             |
| $V_{ICL}$     | Input clamp voltage      | $I_{IN} = 1\text{ mA}$  | 5.5  |      | 7    | V             |
|               |                          | $I_{IN} = -1\text{ mA}$ |      | -0.7 |      | V             |

Table 8. Protection and diagnostics<sup>(1)</sup>

| Symbol      | Parameter                                    | Test conditions                                                                                                                       | Min.          | Typ.          | Max.          | Unit               |
|-------------|----------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------|---------------|---------------|---------------|--------------------|
| $I_{limH}$  | DC Short circuit current                     | $V_{CC} = 13\text{ V}$                                                                                                                | 6             | 8.5           | 12            | A                  |
|             |                                              | $5\text{ V} < V_{CC} < 36\text{ V}$                                                                                                   |               |               | 12            | A                  |
| $I_{limL}$  | Short circuit current during thermal cycling | $V_{CC} = 13\text{ V}; T_R < T_j < T_{TSD}$                                                                                           |               | 3.5           |               | A                  |
| $T_{TSD}$   | Shutdown temperature                         |                                                                                                                                       | 150           | 175           | 200           | $^{\circ}\text{C}$ |
| $T_R$       | Reset temperature                            |                                                                                                                                       | $T_{RS} + 1$  | $T_{RS} + 5$  |               | $^{\circ}\text{C}$ |
| $T_{RS}$    | Thermal reset of STATUS                      |                                                                                                                                       | 135           |               |               | $^{\circ}\text{C}$ |
| $T_{HYST}$  | Thermal hysteresis ( $T_{TSD} - T_R$ )       |                                                                                                                                       |               | 7             |               | $^{\circ}\text{C}$ |
| $V_{DEMAG}$ | Turn-off output voltage clamp                | $I_{OUT} = 1\text{ A}; V_{IN} = 0;$<br>$L = 20\text{ mH}$                                                                             | $V_{CC} - 41$ | $V_{CC} - 46$ | $V_{CC} - 52$ | V                  |
| $V_{ON}$    | Output voltage drop limitation               | $I_{OUT} = 0.03\text{ A};$<br>$T_j = -40\text{ }^{\circ}\text{C}$ to $150\text{ }^{\circ}\text{C}$<br>(see <a href="#">Figure 4</a> ) |               | 25            |               | mV                 |

1. To ensure long term reliability under heavy overload or short circuit conditions, protection and related diagnostic signals must be used together with a proper software strategy. If the device is subjected to abnormal conditions, this software must limit the duration and number of activation cycles

Table 9. Current sense (8V<V<sub>CC</sub><16V)

| Symbol                | Parameter                                                | Test conditions                                                                                                                    | Min.       | Typ.         | Max.         | Unit |
|-----------------------|----------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------|------------|--------------|--------------|------|
| K <sub>0</sub>        | I <sub>OUT</sub> /I <sub>SENSE</sub>                     | I <sub>OUT</sub> = 0.08 A;<br>V <sub>SENSE</sub> = 0.5 V;<br>T <sub>j</sub> = -40°C to 50°C                                        | 850        | 1450         | 2120         |      |
| K <sub>1</sub>        | I <sub>OUT</sub> /I <sub>SENSE</sub>                     | I <sub>OUT</sub> = 0.35 A; V <sub>SENSE</sub> = 0.5V;<br>T <sub>j</sub> = -40°C to 150°C<br>T <sub>j</sub> = 25°C to 150°C         | 840<br>980 | 1360<br>1360 | 2000<br>1740 |      |
| K <sub>2</sub>        | I <sub>OUT</sub> /I <sub>SENSE</sub>                     | I <sub>OUT</sub> = 3A; V <sub>SENSE</sub> = 4V;<br>T <sub>j</sub> = -40°C to 150°C                                                 | 1200       | 1270         | 1350         |      |
| K <sub>3</sub>        | I <sub>OUT</sub> /I <sub>SENSE</sub>                     | I <sub>OUT</sub> = 4A; V <sub>SENSE</sub> = 4V;<br>T <sub>j</sub> = -40°C to 150°C                                                 | 1200       | 1270         | 1350         |      |
| I <sub>SENSE0</sub>   | Analog sense current                                     | I <sub>OUT</sub> = 0A; V <sub>SENSE</sub> = 0V;<br>V <sub>IN</sub> = 0V; T <sub>j</sub> = -40°C to 150°C                           | 0          |              | 1            | μA   |
|                       |                                                          | I <sub>OUT</sub> = 0A; V <sub>SENSE</sub> = 0V;<br>V <sub>IN</sub> = 5V; T <sub>j</sub> = -40°C to 150°C                           | 0          |              | 2            | μA   |
| V <sub>SENSE</sub>    | Max analog sense output voltage                          | I <sub>OUT</sub> = 5A; R <sub>SENSE</sub> = 3.9 kΩ                                                                                 | 5          |              |              | V    |
| V <sub>SENSEH</sub>   | Analog sense output voltage in overtemperature condition | V <sub>CC</sub> = 13V; R <sub>SENSE</sub> = 3.9 kΩ                                                                                 |            | 9            |              | V    |
| I <sub>SENSEH</sub>   | Analog sense output current in overtemperature condition | V <sub>CC</sub> = 13V                                                                                                              |            | 8            |              | mA   |
| t <sub>DSENSE2H</sub> | Delay response time from rising edge of INPUT pin        | V <sub>SENSE</sub> < 4 V; 0.35 A < I <sub>out</sub> < 5 A;<br>I <sub>SENSE</sub> = 90% of I <sub>SENSE</sub> max<br>(see Figure 5) |            | 70           | 300          | μs   |
| t <sub>DSENSE2L</sub> | Delay response time from falling edge of INPUT pin       | V <sub>SENSE</sub> < 4 V; 0.35 A < I <sub>out</sub> < 5 A;<br>I <sub>SENSE</sub> = 10% of I <sub>SENSE</sub> max<br>(see Figure 5) |            | 100          | 250          | μs   |

Figure 3. Switching time waveforms

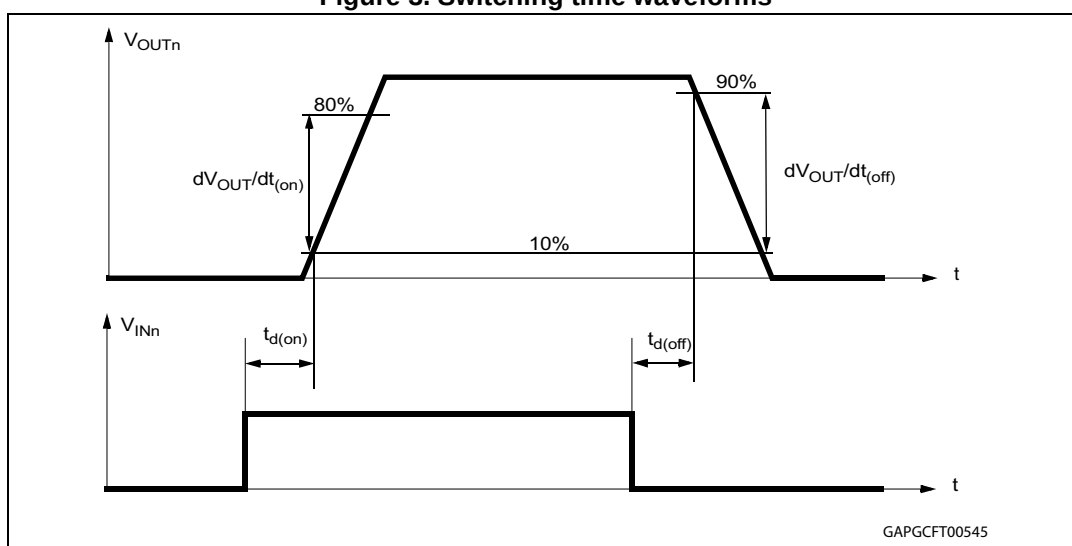


Figure 4. Output voltage drop limitation

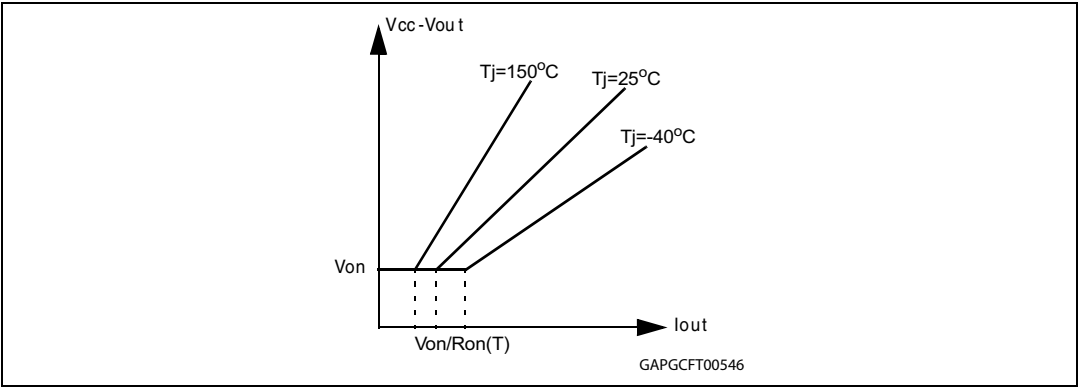
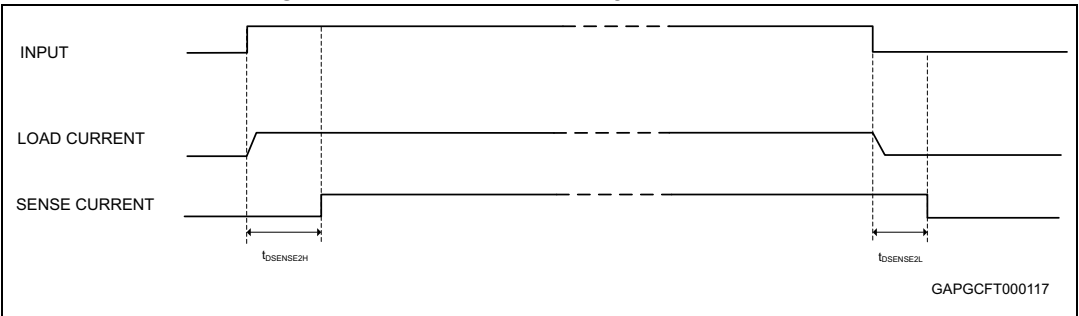


Table 10. Truth table

| Conditions                    | Input | Output | Sense        |
|-------------------------------|-------|--------|--------------|
| Normal operation              | L     | L      | 0            |
|                               | H     | H      | Nominal      |
| Overtemperature               | L     | L      | 0            |
|                               | H     | L      | $V_{SENSEH}$ |
| Undervoltage                  | L     | L      | 0            |
|                               | H     | L      | 0            |
| Short circuit to GND          | L     | L      | 0            |
|                               | H     | L      | 0            |
| Short circuit to $V_{CC}$     | L     | H      | 0            |
|                               | H     | H      | < Nominal    |
| Negative output voltage clamp | L     | L      | 0            |

Figure 5. Current sense delay characteristics



4 Electrical characteristics curves for dual high-side switch

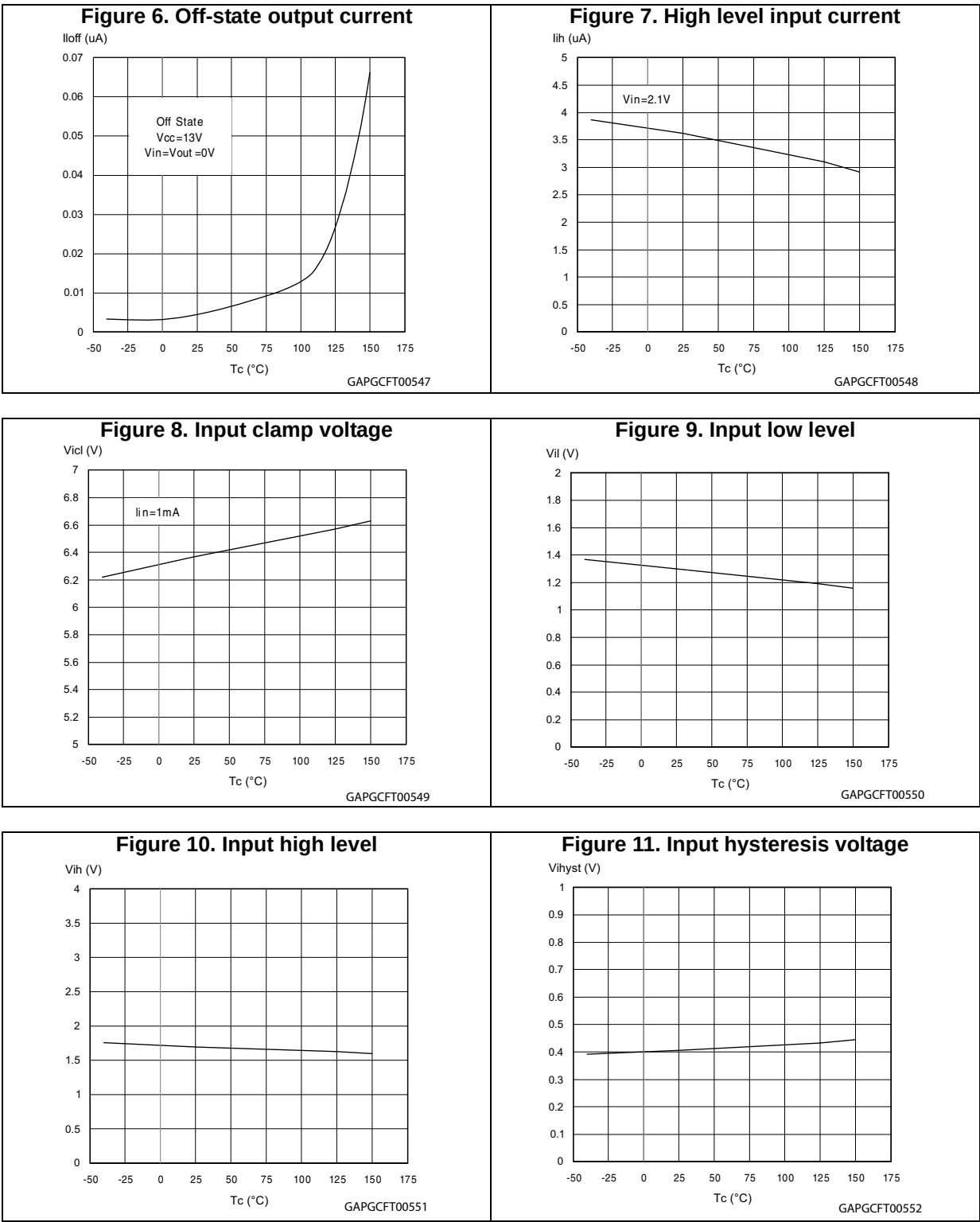


Figure 12. On-state resistance vs  $T_{case}$

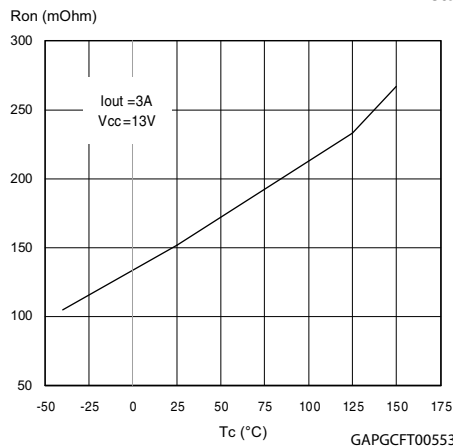


Figure 13. On-state resistance vs  $V_{CC}$

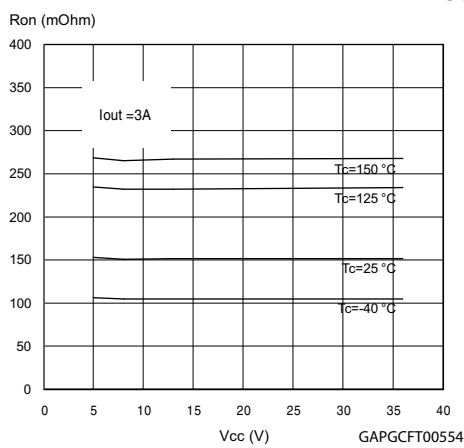


Figure 14. Undervoltage shutdown

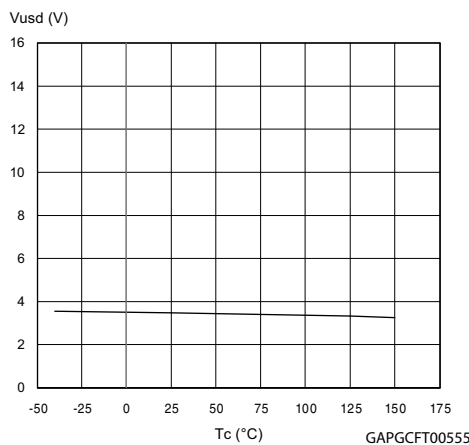


Figure 15. Turn-on voltage slope

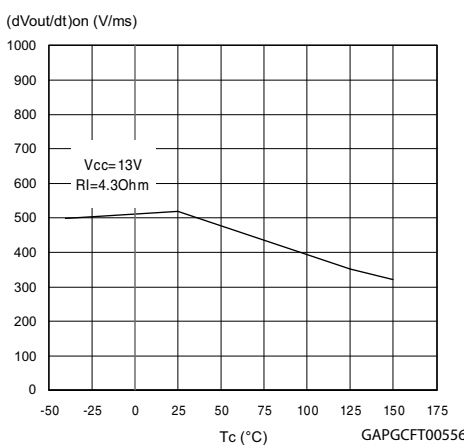


Figure 16.  $I_{LIMH}$  vs  $T_{case}$

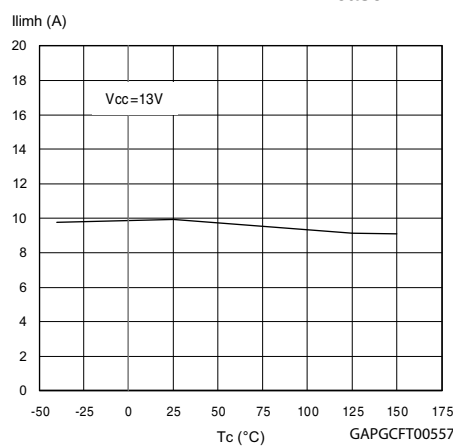
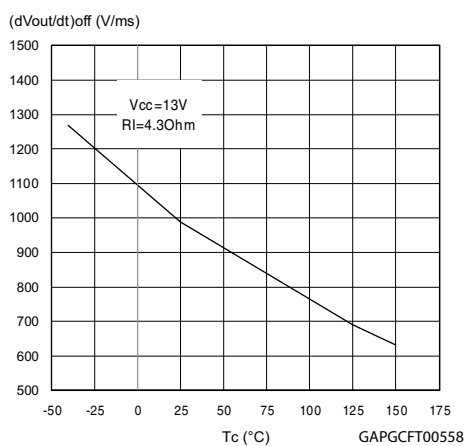


Figure 17. Turn-off voltage slope



## 4.1 Electrical characteristics for low-side switches

Values specified in this section are for  $-40\text{ }^{\circ}\text{C} < T_j < 150\text{ }^{\circ}\text{C}$ , unless otherwise specified

**Table 11. Off**

| Symbol             | Parameter                                                         | Test conditions                                                                             | Min  | Typ | Max  | Unit          |
|--------------------|-------------------------------------------------------------------|---------------------------------------------------------------------------------------------|------|-----|------|---------------|
| $V_{\text{CLAMP}}$ | Drain-source clamp voltage                                        | $V_{\text{IN}} = 0\text{ V}; I_{\text{D}} = 1.5\text{ A}$                                   | 40   | 45  | 55   | V             |
| $V_{\text{CLTH}}$  | Drain-source clamp threshold voltage                              | $V_{\text{IN}} = 0\text{ V}; I_{\text{D}} = 2\text{ mA}$                                    | 36   |     |      | V             |
| $V_{\text{INTH}}$  | Input threshold voltage                                           | $V_{\text{DS}} = V_{\text{IN}}; I_{\text{D}} = 1\text{ mA}$                                 | 0.5  |     | 2.5  | V             |
| $I_{\text{ISS}}$   | Supply current from input pin                                     | $V_{\text{DS}} = 0\text{ V}; V_{\text{IN}} = 5\text{ V}$                                    |      | 100 | 150  | $\mu\text{A}$ |
| $V_{\text{INCL}}$  | Input-source clamp voltage                                        | $I_{\text{IN}} = 1\text{ mA}$                                                               | 6    | 6.8 | 8    | V             |
|                    |                                                                   | $I_{\text{IN}} = -1\text{ mA}$                                                              | -1.0 |     | -0.3 | V             |
| $I_{\text{DSS}}$   | Zero input voltage drain current ( $V_{\text{IN}} = 0\text{ V}$ ) | $V_{\text{DS}} = 13\text{ V}; V_{\text{IN}} = 0\text{ V}; T_j = 25\text{ }^{\circ}\text{C}$ |      |     | 30   | $\mu\text{A}$ |
|                    |                                                                   | $V_{\text{DS}} = 25\text{ V}; V_{\text{IN}} = 0\text{ V}$                                   |      |     | 75   | $\mu\text{A}$ |

**Table 12. On**

| Symbol              | Parameter                         | Test conditions                                                                           | Min | Typ | Max | Unit             |
|---------------------|-----------------------------------|-------------------------------------------------------------------------------------------|-----|-----|-----|------------------|
| $R_{\text{DS(on)}}$ | Static drain-source on resistance | $V_{\text{IN}} = 5\text{ V}; I_{\text{D}} = 3\text{ A}; T_j = 25\text{ }^{\circ}\text{C}$ | —   | —   | 120 | $\text{m}\Omega$ |
|                     |                                   | $V_{\text{IN}} = 5\text{ V}; I_{\text{D}} = 3\text{ A}$                                   | —   | —   | 240 | $\text{m}\Omega$ |

**Table 13. Dynamic ( $T_j = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)**

| Symbol           | Parameter                | Test conditions                                                             | Min | Typ | Max | Unit |
|------------------|--------------------------|-----------------------------------------------------------------------------|-----|-----|-----|------|
| $g_{\text{fs}}$  | Forward transconductance | $V_{\text{DD}} = 13\text{ V}; I_{\text{D}} = 1.5\text{ A}$                  | —   | 2.5 | —   | S    |
| $C_{\text{OSS}}$ | Output capacitance       | $V_{\text{DS}} = 13\text{ V}; f = 1\text{ MHz}; V_{\text{IN}} = 0\text{ V}$ | —   | 150 | —   | pF   |

**Table 14. Switching ( $T_j = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)**

| Symbol              | Parameter           | Test conditions                                                                                                                               | Min | Typ  | Max  | Unit          |
|---------------------|---------------------|-----------------------------------------------------------------------------------------------------------------------------------------------|-----|------|------|---------------|
| $t_{\text{d(on)}}$  | Turn-on delay time  | $V_{\text{DD}} = 15\text{ V}; I_{\text{D}} = 3\text{ A}; V_{\text{gen}} = 5\text{ V}; R_{\text{gen}} = R_{\text{IN MIN}} = 220\text{ }\Omega$ | —   | 200  | 400  | ns            |
| $t_{\text{r}}$      | Rise time           |                                                                                                                                               | —   | 1.2  | 2.5  | $\mu\text{s}$ |
| $t_{\text{d(off)}}$ | Turn-off delay time |                                                                                                                                               | —   | 600  | 1350 | ns            |
| $t_{\text{f}}$      | Fall time           |                                                                                                                                               | —   | 400  | 1000 | ns            |
| $t_{\text{d(on)}}$  | Turn-on delay time  | $V_{\text{DD}} = 15\text{ V}; I_{\text{D}} = 3\text{ A}; V_{\text{gen}} = 5\text{ V}; R_{\text{gen}} = 2.2\text{ k}\Omega$                    | —   | 0.80 | 2.5  | $\mu\text{s}$ |
| $t_{\text{r}}$      | Rise time           |                                                                                                                                               | —   | 3.7  | 7.5  | $\mu\text{s}$ |
| $t_{\text{d(off)}}$ | Turn-off delay time |                                                                                                                                               | —   | 2.6  | 7.5  | $\mu\text{s}$ |
| $t_{\text{f}}$      | Fall time           |                                                                                                                                               | —   | 2.3  | 7.0  | $\mu\text{s}$ |



Table 14. Switching ( $T_j = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified) (continued)

| Symbol         | Parameter             | Test conditions                                                                                                  | Min | Typ | Max | Unit       |
|----------------|-----------------------|------------------------------------------------------------------------------------------------------------------|-----|-----|-----|------------|
| $(di/dt)_{on}$ | Turn-on current slope | $V_{DD} = 15\text{ V}$ ; $I_D = 3\text{ A}$ ; $V_{gen} = 5\text{ V}$ ;<br>$R_{gen} = R_{IN\ MINn} = 220\ \Omega$ | —   | 3.0 |     | A/ $\mu$ s |
| $Q_i$          | Total input charge    | $V_{DD} = 12\text{ V}$ ; $I_D = 3\text{ A}$ ; $V_{IN} = 5\text{ V}$ ;<br>$I_{gen} = 2.13\text{ mA}$              | —   | 9.0 |     | nC         |

Table 15. Source drain diode

| Symbol         | Parameter                | Test conditions                                                                                         | Min | Typ | Max | Unit |
|----------------|--------------------------|---------------------------------------------------------------------------------------------------------|-----|-----|-----|------|
| $V_{SD}^{(1)}$ | Forward on voltage       | $I_{SD} = 1.5\text{ A}$ ; $V_{IN} = 0\text{ V}$                                                         | —   | 0.8 | —   | V    |
| $t_{rr}$       | Reverse recovery time    | $I_{SD} = 1.5\text{ A}$ ; $di/dt = 12\text{ A/ms}$ ;<br>$V_{DD} = 30\text{ V}$ ; $L = 200\ \mu\text{H}$ | —   | 400 | —   | ns   |
| $Q_{rr}$       | Reverse recovery charge  |                                                                                                         | —   | 200 | —   | nC   |
| $I_{RRM}$      | Reverse recovery current |                                                                                                         | —   | 1.0 | —   | A    |

1. Pulsed: pulse duration = 300 $\mu$ s, duty cycle 1.5%

Table 16. Protection and diagnostics ( $-40\text{ }^{\circ}\text{C} < T_j < 150\text{ }^{\circ}\text{C}$ , unless otherwise specified)

| Symbol     | Parameter                     | Test conditions                                                                                                                                                  | Min | Typ | Max | Unit               |
|------------|-------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|-----|-----|--------------------|
| $I_{lim}$  | Drain current limit           | $V_{IN} = 5\text{ V}$ ; $V_{DS} = 13\text{ V}$                                                                                                                   | 6   | 8.5 | 12  | A                  |
| $t_{dlim}$ | Step response current limit   | $V_{IN} = 5\text{ V}$ ; $V_{DS} = 13\text{ V}$                                                                                                                   |     | 10  |     | $\mu$ s            |
| $T_{jsh}$  | Overtemperature shutdown      |                                                                                                                                                                  | 150 | 175 | 200 | $^{\circ}\text{C}$ |
| $T_{jrs}$  | Overtemperature reset         |                                                                                                                                                                  | 135 |     |     | $^{\circ}\text{C}$ |
| $I_{gf}$   | Fault sink current            | $V_{IN} = 5\text{ V}$ ; $V_{DS} = 13\text{ V}$ ; $T_j = T_{jsh}$                                                                                                 | 10  | 15  | 20  | mA                 |
| $E_{as}$   | Single pulse avalanche energy | Starting $T_j = 25\text{ }^{\circ}\text{C}$ ; $V_{DD} = 24\text{ V}$ ;<br>$V_{IN} = 5\text{ V}$ ; $R_{gen} = R_{IN\ MINn} = 220\ \Omega$ ;<br>$L = 24\text{ mH}$ | 100 |     |     | mJ                 |

4.2 Electrical characteristics curves for low-side switches

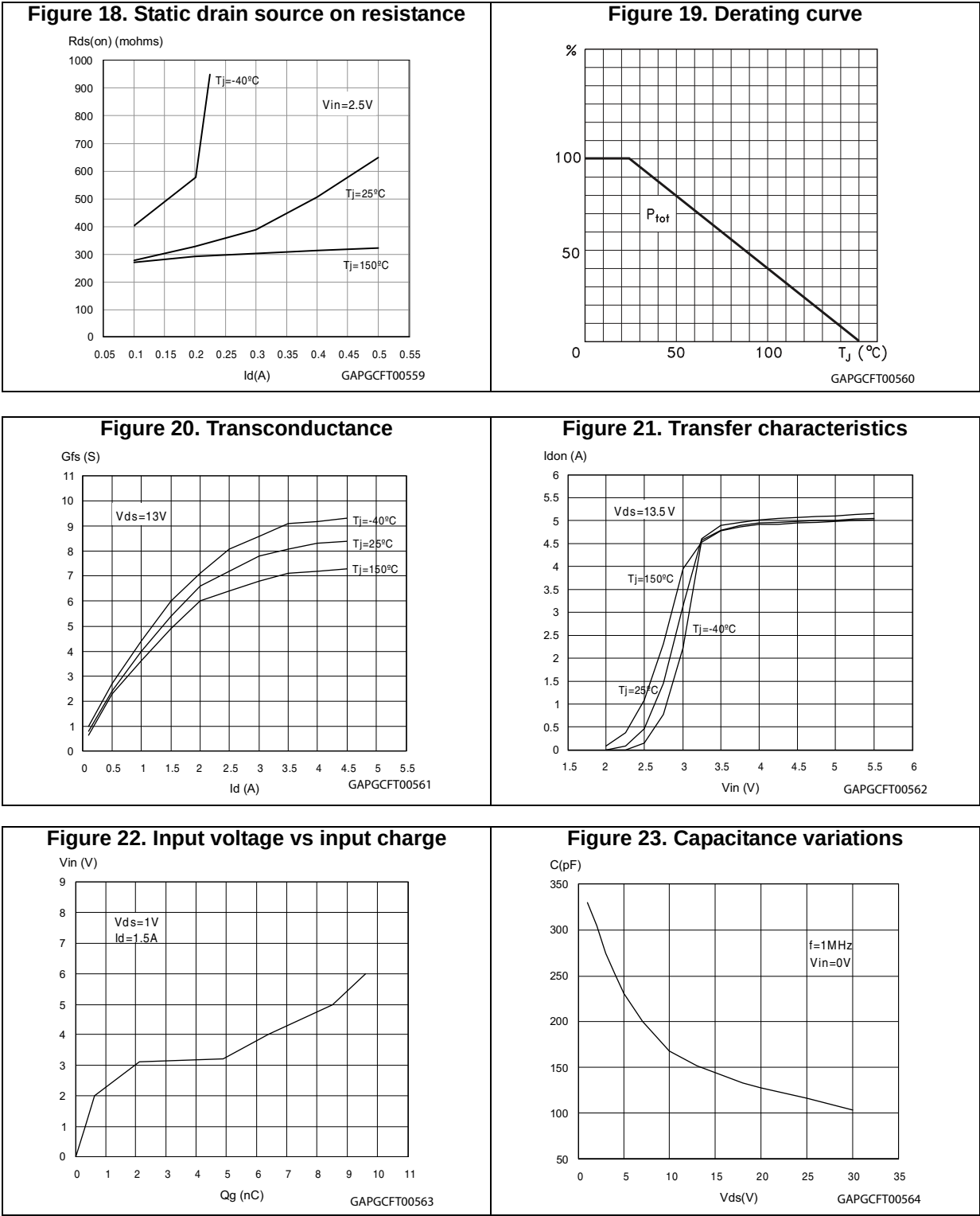


Figure 24. Output characteristics

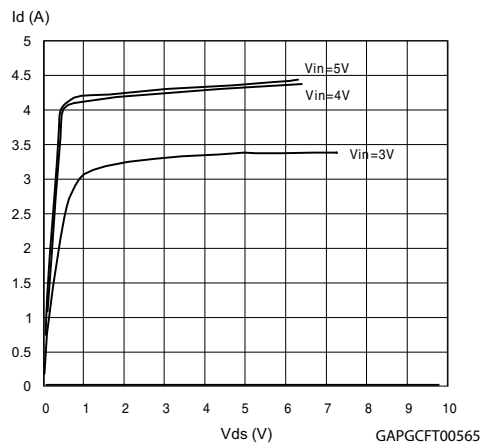


Figure 25. Step response current limit

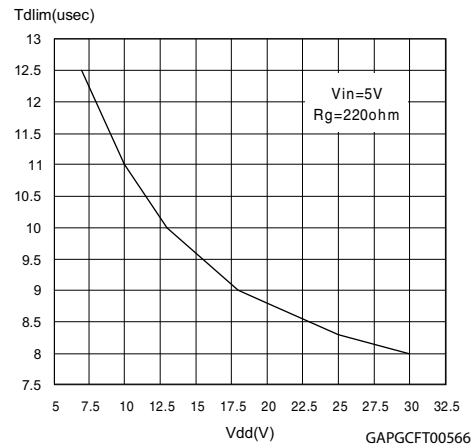


Figure 26. Source-drain diode forward characteristics

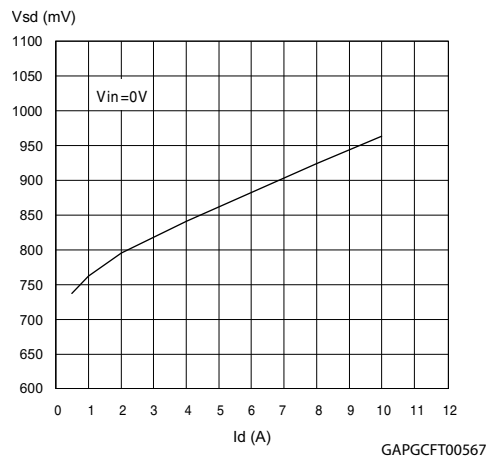
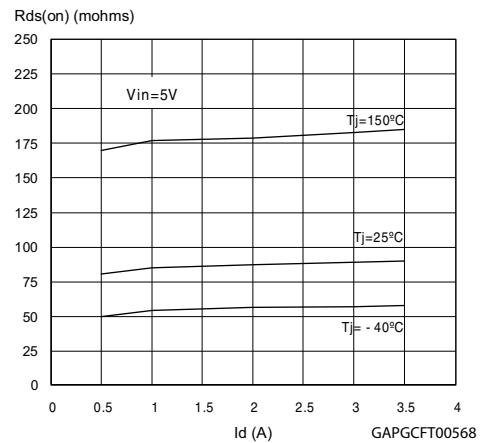
Figure 27. Static drain-source on resistance vs  $I_D$ 

Figure 28. Static drain-source on resistance vs input voltage (part 1)

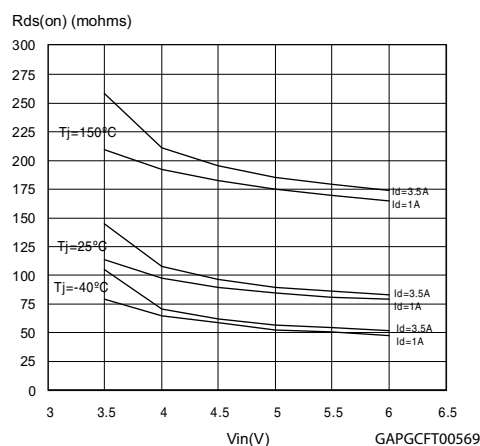
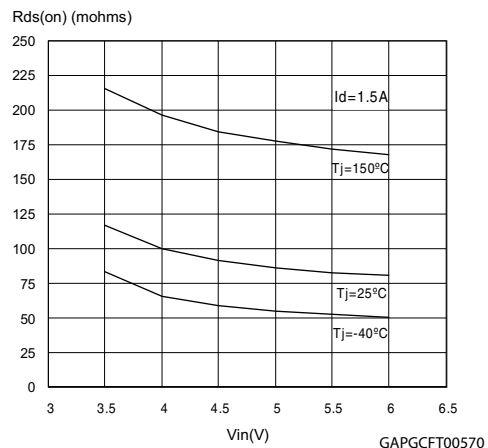
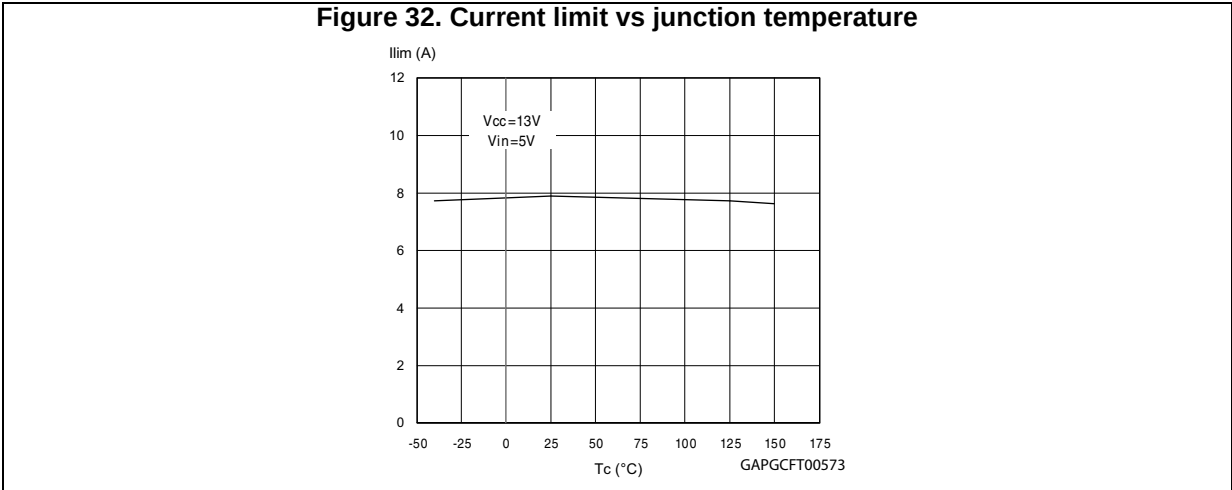
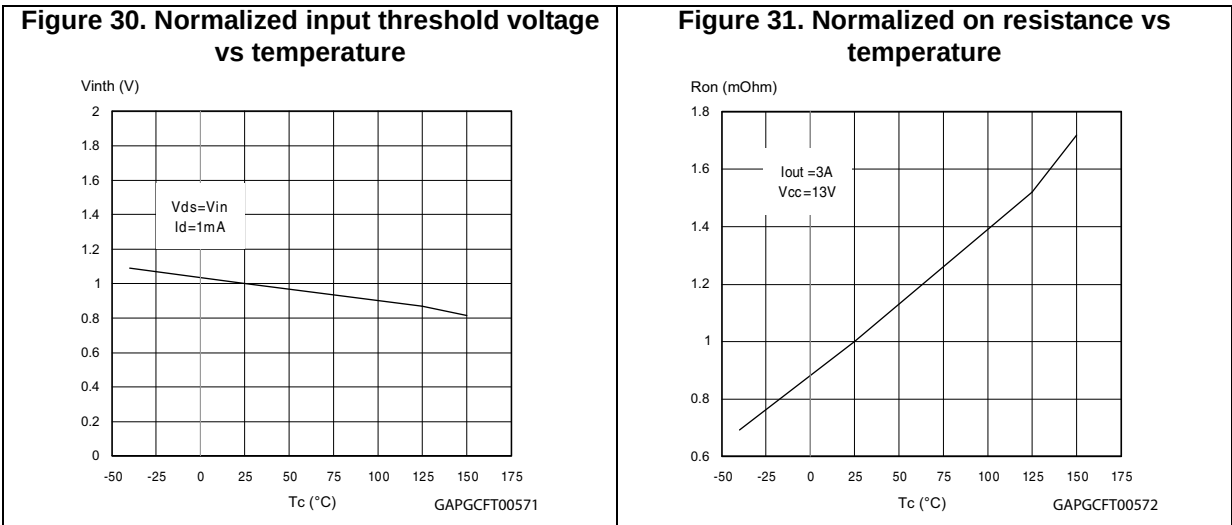


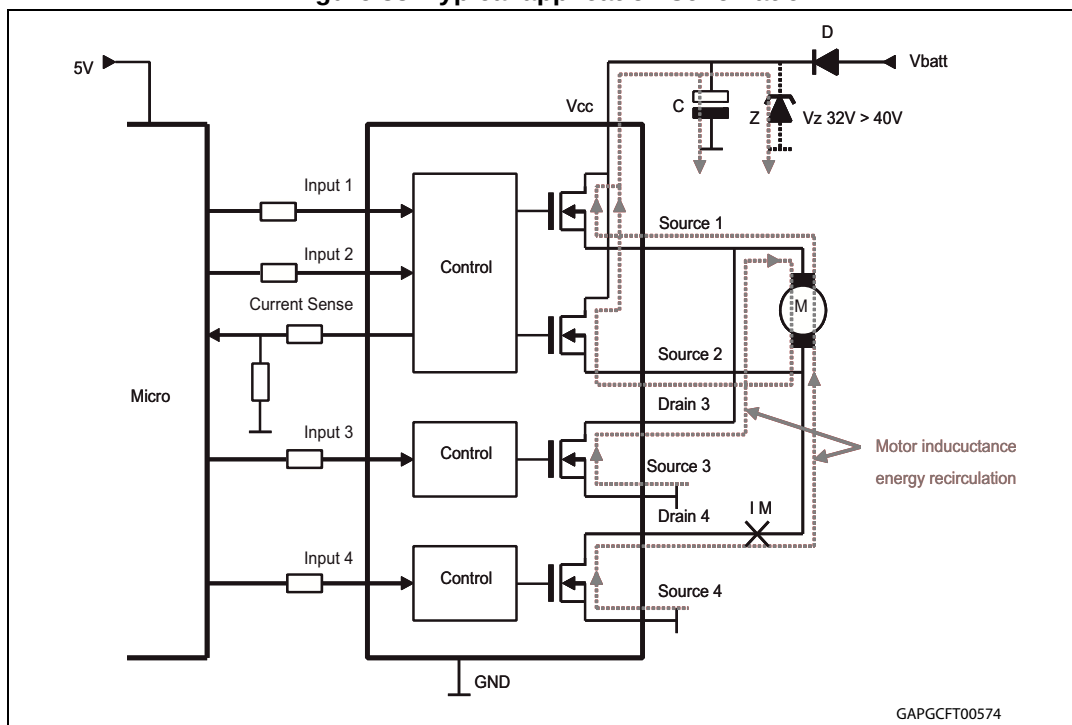
Figure 29. Static drain-source on resistance vs input voltage (part 2)





## 5 Application information

Figure 33. Typical application schematic



**Note:** Mostly motor bridge drivers use a reverse battery protection diode (D) inside supply rail. This diode prevents a reverse current flow back to Vbatt in case the bridge gets disabled via the logic inputs while motor inductance still carries energy. In order to prevent a hazardous overvoltage at circuit supply terminal (Vcc), a blocking capacitor (C) is needed to limit the voltage overshoot. As basic orientation, 50  $\mu$ F per 1 A load current is recommended. In alternative, also a Zener protection (Z) is suitable. Even if a reverse polarity diode is not present, it is recommended to use a capacitor or zener at Vcc because a similar problem appears in case supply terminal of the module has intermittent electrical contact to the battery or gets disconnected while motor is operating.

Figure 34. Recommended motor operation

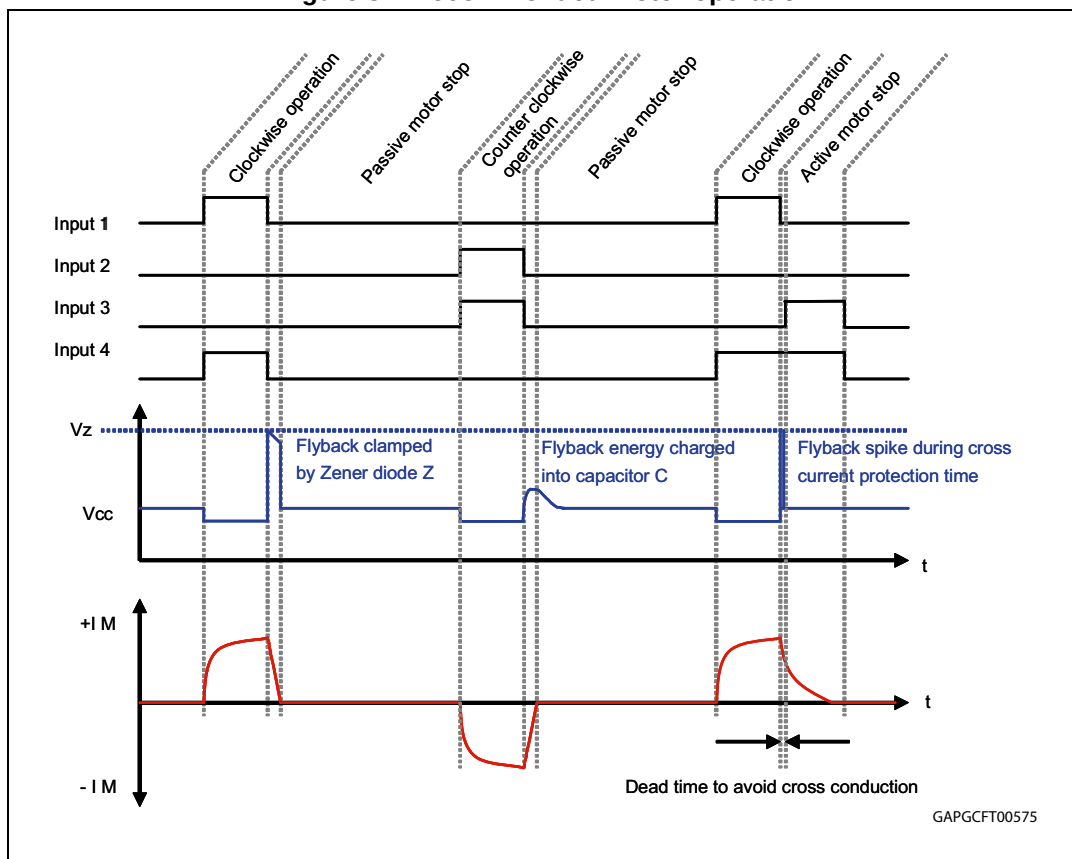
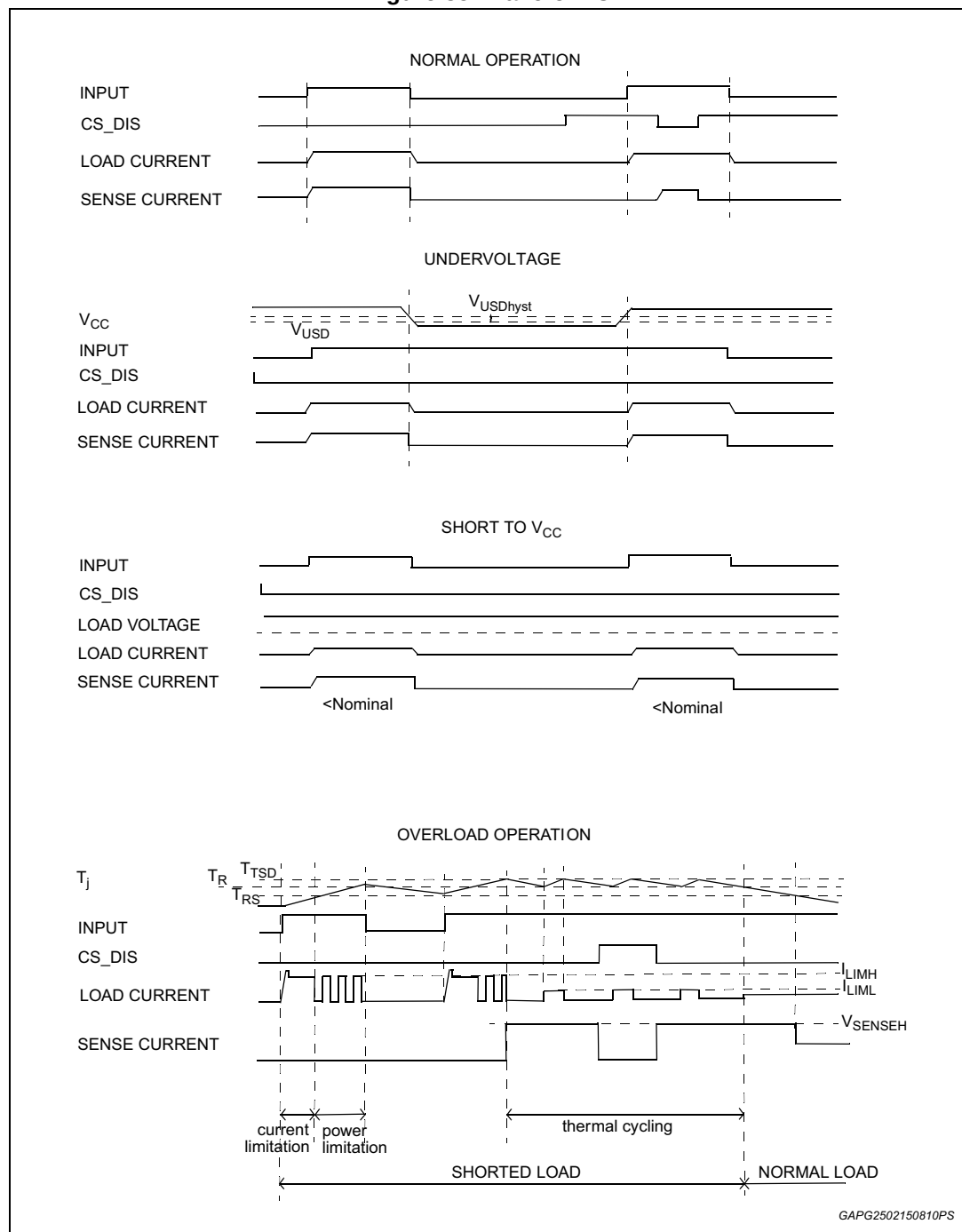
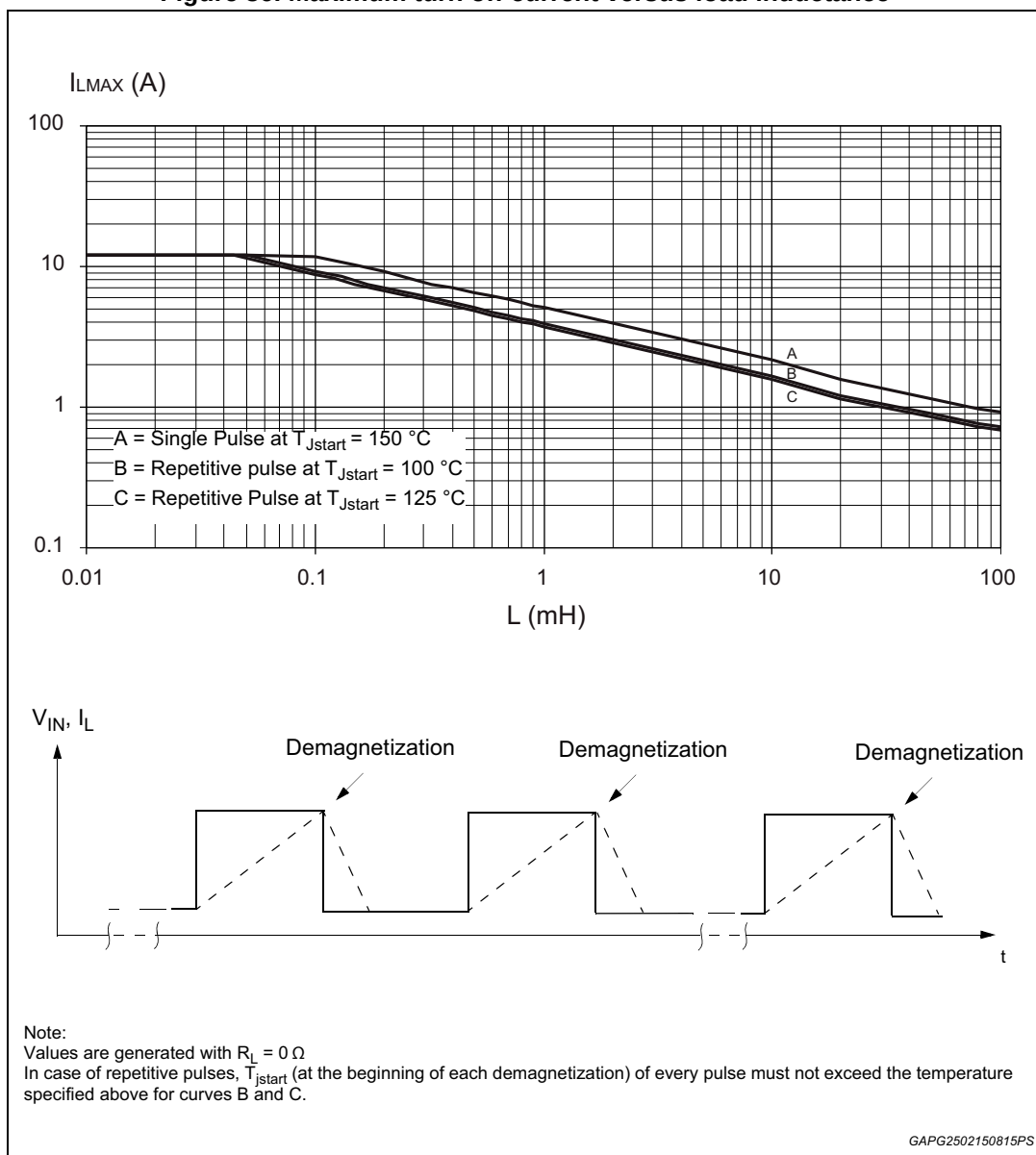


Figure 35. Waveforms



## 5.1 Maximum demagnetization energy ( $V_{CC} = 13.5\text{ V}$ )

Figure 36. Maximum turn off current versus load inductance

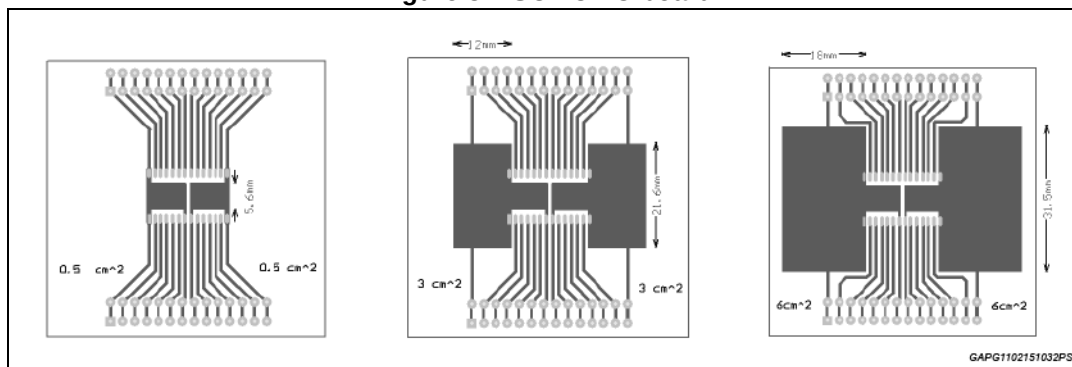




## 6 Package and thermal data

### 6.1 SO-28 thermal data

Figure 37. SO-28 PC board



Note: Layout condition of  $R_{th}$  and  $Z_{th}$  measurements (PCB FR4 area= 58 mm x 58 mm, PCB thickness = 2 mm, Cu thickness = 35  $\mu m$ , Copper areas: from minimum pad layout to 16  $cm^2$ ).

Figure 38. Chipset configuration

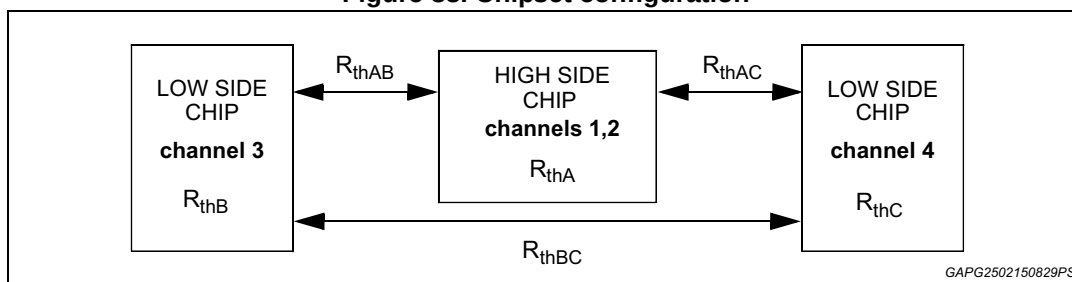
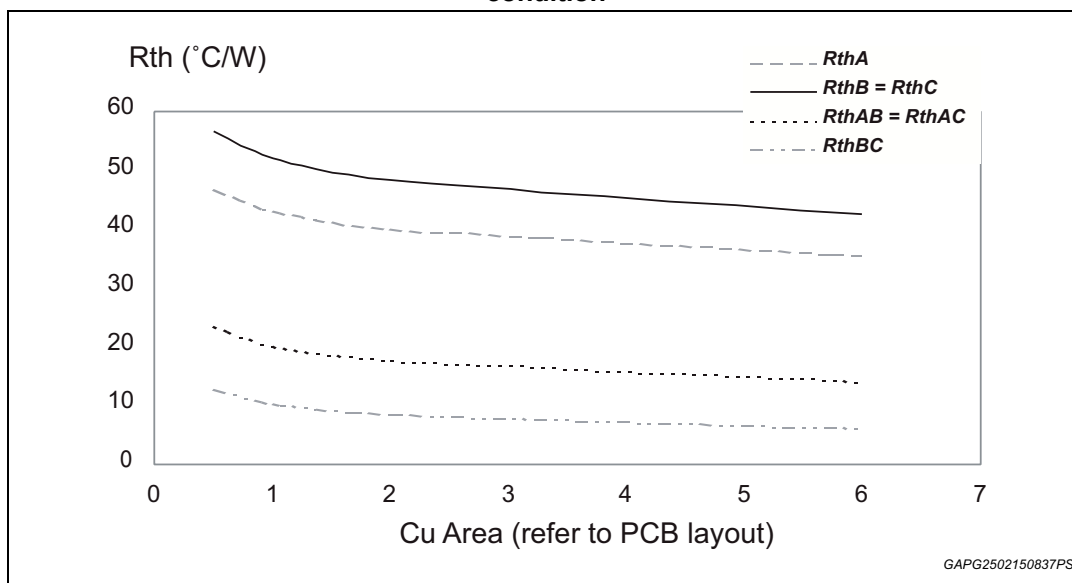


Figure 39. Auto and mutual  $R_{thj-amb}$  vs PCB copper area in open box free air condition



Note: See Figure 38. For more detailed information see Table 17 and Table 18.

Table 17. Thermal calculations in clockwise and anti-clockwise operation in steady-state mode

| HS <sub>1</sub> | HS <sub>2</sub> | LS <sub>3</sub> | LS <sub>4</sub> | $T_{jHS12}$                                                       | $T_{jLS3}$                                                          | $T_{jLS4}$                                                          |
|-----------------|-----------------|-----------------|-----------------|-------------------------------------------------------------------|---------------------------------------------------------------------|---------------------------------------------------------------------|
| ON              | OFF             | OFF             | ON              | $P_{dHS1} \times R_{thHS} + P_{dLS4} \times R_{thHSLS} + T_{amb}$ | $P_{dHS1} \times R_{thHSLS} + P_{dLS4} \times R_{thLSLS} + T_{amb}$ | $P_{dHS1} \times R_{thHSLS} + P_{dLS4} \times R_{thLS} + T_{amb}$   |
| OFF             | ON              | ON              | OFF             | $P_{dHS2} \times R_{thHS} + P_{dLS3} \times R_{thHSLS} + T_{amb}$ | $P_{dHS2} \times R_{thHSLS} + P_{dLS3} \times R_{thLS} + T_{amb}$   | $P_{dHS2} \times R_{thHSLS} + P_{dLS3} \times R_{thLSLS} + T_{amb}$ |

Table 18. Thermal resistances definitions

| Parameter                                  | Definition                                                                                             |
|--------------------------------------------|--------------------------------------------------------------------------------------------------------|
| $R_{thHS} = R_{thHS1} = R_{thHS2}$         | High-side chip thermal resistance junction to ambient (HS <sub>1</sub> or HS <sub>2</sub> in ON-state) |
| $R_{thLS} = R_{thLS3} = R_{thLS4}$         | Low-side chip thermal resistance junction to ambient                                                   |
| $R_{thHSLS} = R_{thHS1LS4} = R_{thHS2LS3}$ | Mutual thermal resistance junction to ambient between high-side and low-side chips                     |
| $R_{thLSLS} = R_{thLS3LS4}$                | Mutual thermal resistance junction to ambient between low-side chips                                   |

Note: Values dependent on PCB heatsink area.

Table 19. Single pulse thermal impedance definitions

| Parameter                                    | Definition                                                                        |
|----------------------------------------------|-----------------------------------------------------------------------------------|
| $Z_{thHS}$                                   | High-side chip thermal impedance junction to ambient                              |
| $Z_{thLS} = Z_{thLS3} = Z_{thLS4}$           | Low-side chip thermal impedance junction to ambient                               |
| $Z_{thHLSL} = Z_{thHS12LS3} = Z_{thHS12LS4}$ | Mutual thermal impedance junction to ambient between high-side and low-side chips |
| $Z_{thLSLS} = Z_{thLS3LS4}$                  | Mutual thermal impedance junction to ambient between low-side chips               |

Note: Values dependent on PCB heatsink area.

Table 20. Thermal calculations in transient mode

| Parameter   | Definition                                                                                      |
|-------------|-------------------------------------------------------------------------------------------------|
| $T_{jHS12}$ | $Z_{thHS} \times P_{dHS12} + Z_{thHLSL} \times (P_{dLS3} + P_{dLS4}) + T_{amb}$                 |
| $T_{jLS3}$  | $Z_{thHLSL} \times P_{dHS12} + Z_{thLS} \times P_{dLS3} + Z_{thLSLS} \times P_{dLS4} + T_{amb}$ |
| $T_{jLS4}$  | $Z_{thHLSL} \times P_{dHS12} + Z_{thLSLS} \times P_{dLS3} + Z_{thLS} \times P_{dLS4} + T_{amb}$ |

Note: Calculation is valid in any dynamic operating condition. Pd values set by user.

Figure 40. SO-28 HSD thermal impedance junction ambient single pulse

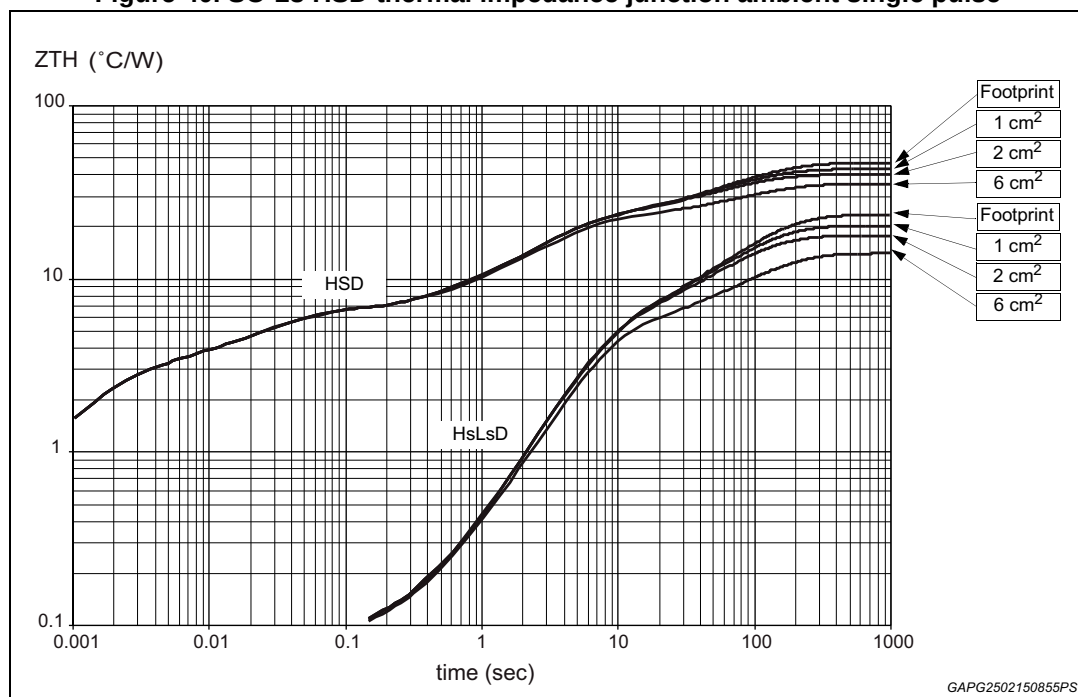
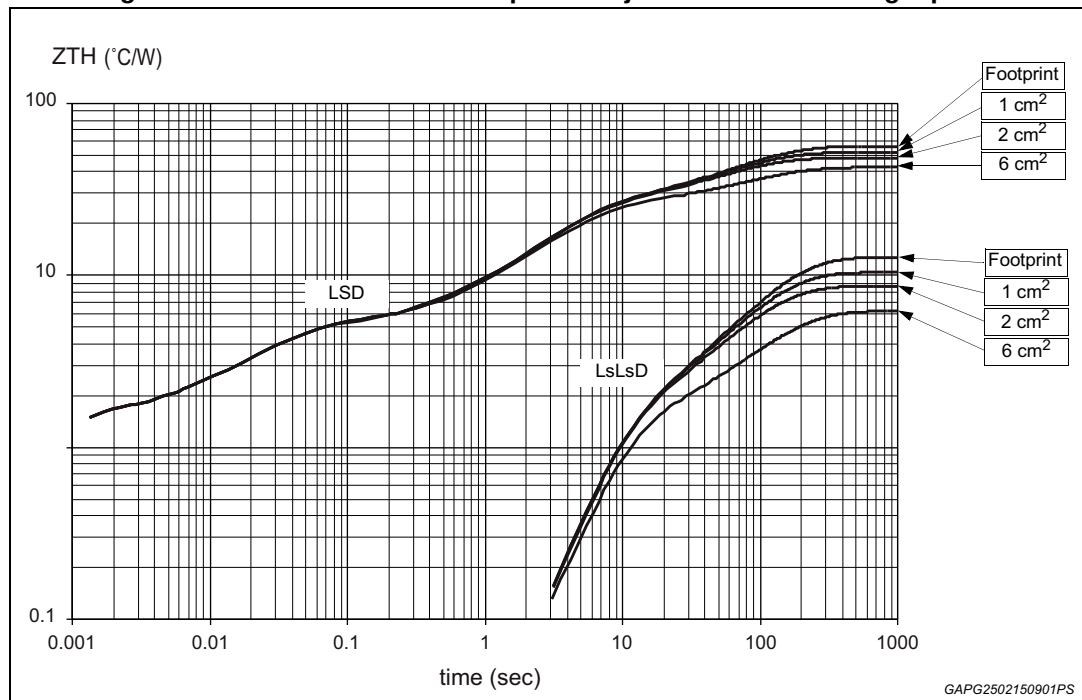


Figure 41. SO-28 LSD thermal impedance junction ambient single pulse



Equation 1: pulse calculation formula

$$Z_{TH\delta} = R_{TH} \cdot \delta + Z_{THtp}(1 - \delta)$$

$$\text{where } \delta = t_p / T$$

Figure 42. Thermal fitting model of an H-bridge in SO-28

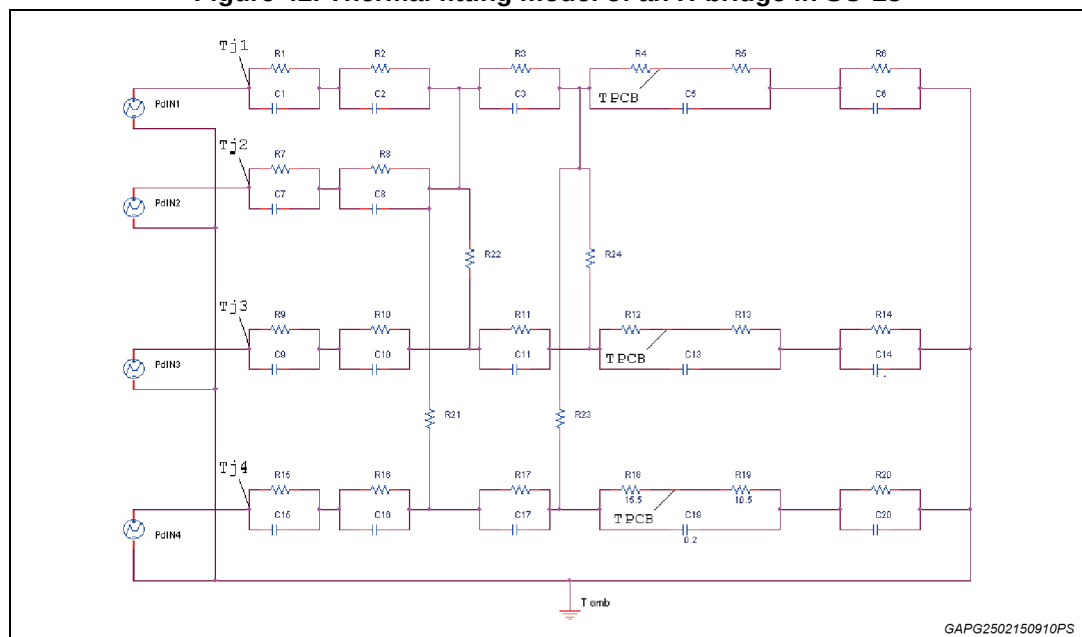


Table 21. Thermal parameters

| Areal/island (cm <sup>2</sup> ) | Footprint | 1     | 2     | 6     |
|---------------------------------|-----------|-------|-------|-------|
| R1 = R7 (°C/W)                  | 1         |       |       |       |
| R2 = R8 (°C/W)                  | 1.8       |       |       |       |
| R3 = R11 = R17 (°C/W)           | 3.5       |       |       |       |
| R4 (°C/W)                       | 13.5      |       |       |       |
| R5 = R13 = R19 (°C/W)           | 10.5      |       |       |       |
| R6 = R14 = R20 (°C/W)           | 62.28     | 52.28 | 44.28 | 32.28 |
| R9 = R15 (°C/W)                 | 0.24      |       |       |       |
| R10 = R16 (°C/W)                | 1.2       |       |       |       |
| R12 (°C/W)                      | 15.2      |       |       |       |
| R18 (°C/W)                      | 15.5      |       |       |       |
| R21 = R22 = R23 (°C/W)          | 150       |       |       |       |
| R24 (°C/W)                      | 150       | 52.28 | 44.28 | 32.28 |
| C1 = C7 (W·s/°C)                | 0.0008    |       |       |       |
| C2 = C8 (W·s/°C)                | 0.001     |       |       |       |
| C3 = C11 = C17 (W·s/°C)         | 0.008     |       |       |       |
| C5 = C13 = C19 (W·s/°C)         | 0.2       |       |       |       |
| C6 = C14 = C20 (W·s/°C)         | 1.6       | 1.61  | 1.7   | 3.25  |
| C9 = C15 (W·s/°C)               | 0.00015   |       |       |       |
| C10 = C16 (W·s/°C)              | 0.0005    |       |       |       |

Note: A blank space means that the value is the same as the previous one.

## 7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

### 7.1 SO-28 package information

Figure 43. SO-28 package outline

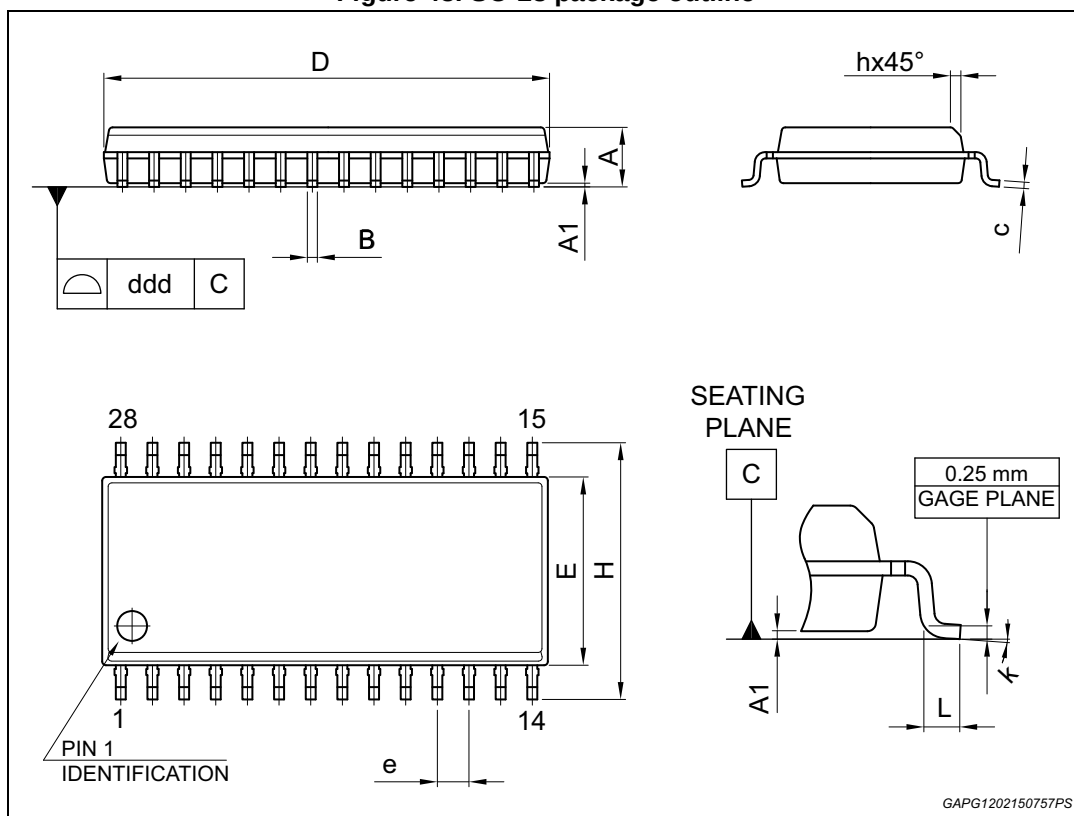


Table 22. SO-28 mechanical data

| Ref.             | Dimensions  |      |       |
|------------------|-------------|------|-------|
|                  | Millimeters |      |       |
|                  | Min.        | Typ. | Max.  |
| A                | 2.35        |      | 2.65  |
| A1               | 0.10        |      | 0.30  |
| B                | 0.33        |      | 0.51  |
| C                | 0.23        |      | 0.32  |
| D <sup>(1)</sup> | 17.70       |      | 18.10 |

Table 22. SO-28 mechanical data

| Ref. | Dimensions  |      |       |
|------|-------------|------|-------|
|      | Millimeters |      |       |
|      | Min.        | Typ. | Max.  |
| E    | 7.40        |      | 7.60  |
| e    |             | 1.27 |       |
| H    | 10.0        |      | 10.65 |
| h    | 0.25        |      | 0.75  |
| L    | 0.40        |      | 1.27  |
| k    | 0°          |      | 8°    |
| ddd  |             |      | 0.10  |

1. Dimension "D" does not include mold flash, protrusions or gate burrs.  
Mold flash, protrusions or gate burrs shall not exceed 0.15mm per side.

## 7.2 SO-28 packing information

Figure 44. SO-28 tube shipment (no suffix)

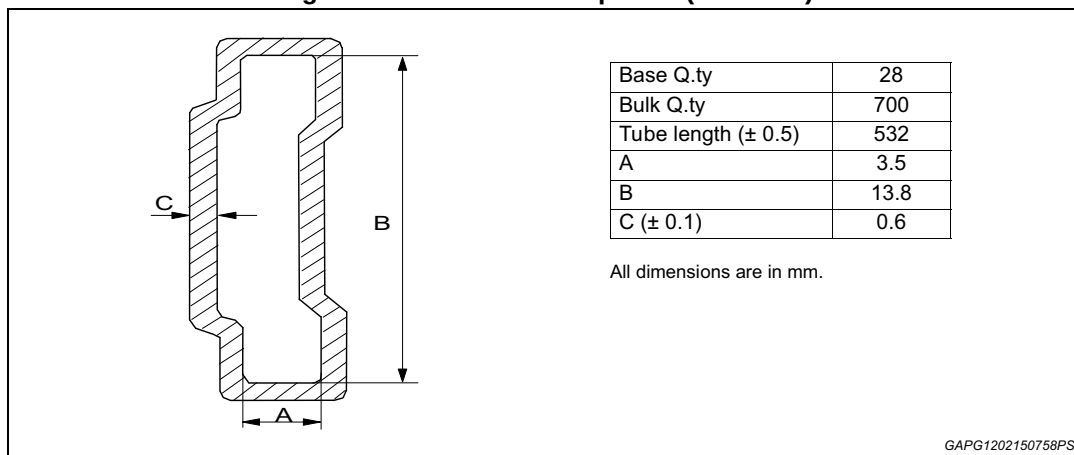


Figure 45. Reel for SO-28

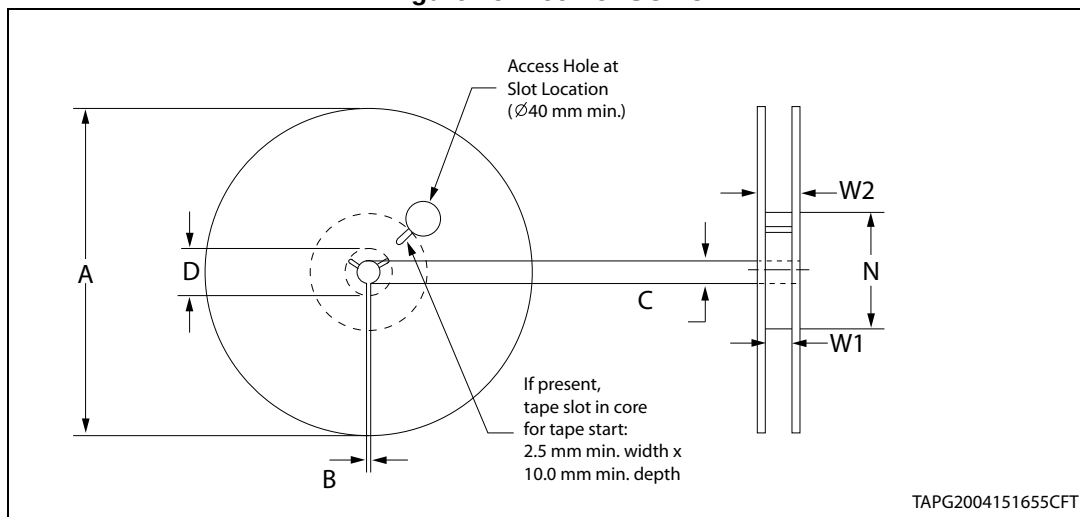


Table 23. Reel dimensions

| Description    | Value <sup>(1)</sup> |
|----------------|----------------------|
| Base quantity  | 1000                 |
| Bulk quantity  | 1000                 |
| A (max)        | 330                  |
| B (min)        | 1.5                  |
| C (+0.5, -0.2) | 13                   |
| D (min)        | 20.2                 |
| N              | 100                  |
| W1 (+2/ -0)    | 24.4                 |
| W2 (max)       | 30.4                 |

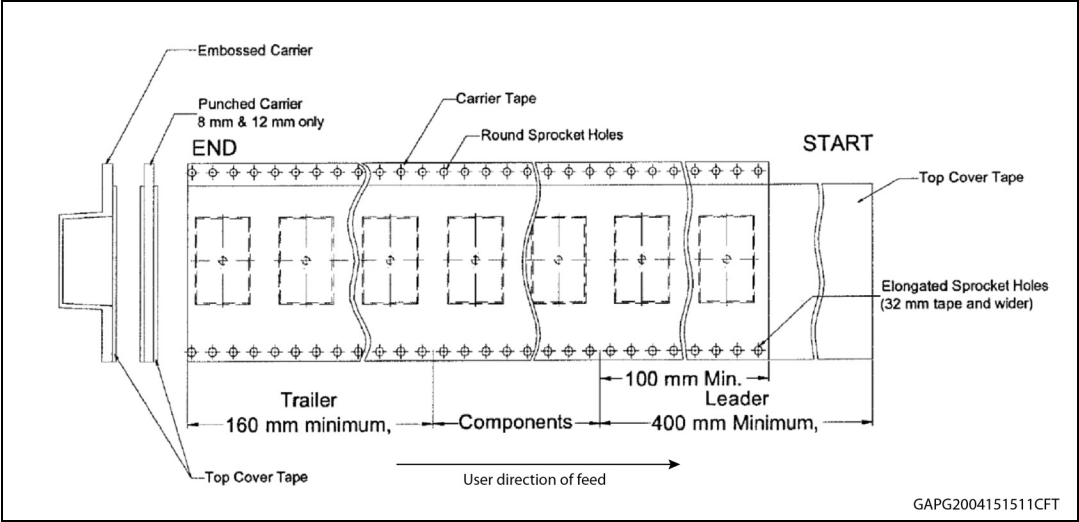
1. All dimensions are in mm.



| Description    | Value <sup>(1)</sup> |
|----------------|----------------------|
| A <sub>0</sub> | 10.90 ± 0.1          |
| B <sub>0</sub> | 18.55 ± 0.1          |
| K <sub>0</sub> | 3.0 ± 0.1            |
| K <sub>1</sub> | 2.6 ± 0.1            |
| F              | 11.5 ± 0.1           |
| P <sub>1</sub> | 12.0 ± 0.1           |
| D1             | 1.5 ± 0.1            |
| W              | 24.0 ± 0.3           |



Figure 47. SO-28 schematic drawing of leader and trailer tape



## 8 Order codes

**Table 25. Device summary**

| Package | Order codes |               |
|---------|-------------|---------------|
|         | Tube        | Tape and reel |
| SO-28   | VN5770AKP-E | VN5770AKPTR-E |

## 9 Revision history

**Table 26. Document revision history**

| Date        | Revision | Changes                                                                                                                                           |
|-------------|----------|---------------------------------------------------------------------------------------------------------------------------------------------------|
| 11-Nov-2010 | 1        | Initial release.                                                                                                                                  |
| 04-Jan-2012 | 2        | <a href="#">Table 9: Current sense (8V&lt;VCC&lt;16V)</a> - K <sub>0</sub> values modified                                                        |
| 20-Feb-2012 | 3        | Update <a href="#">Figure 2: Configuration diagram (top view)</a> and <a href="#">Figure 33: Typical application schematic</a>                    |
| 02-Oct-2012 | 4        | <a href="#">Table 9: Current sense (8V&lt;VCC&lt;16V)</a> :<br>– K <sub>0</sub> : updated values                                                  |
| 23-Sep-2013 | 5        | Updated Disclaimer<br>Fixed order code value on the cover page and <a href="#">Table 25: Device summary</a>                                       |
| 25-Feb-2015 | 6        | Updated:<br>– <a href="#">Section 7.1: SO-28 package information</a> ;<br>– Tape dimensions in <a href="#">Figure 8: Order codes on page 35</a> . |
| 21-Jul-2015 | 7        | Updated <a href="#">Section 7.2: SO-28 packing information</a>                                                                                    |

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